

# 2N6287 COMPLEMENTARY SILICON POWER DARLINGTON TRANSISTORS

2N6284

- STMicroelectronics PREFERRED SALESTYPES
- COMPLEMENTARY PNP NPN DEVICES
- INTEGRATED ANTIPARALLEL COLLECTOR-EMITTER DIODE

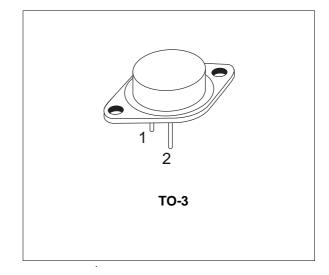
#### **APPLICATIONS**

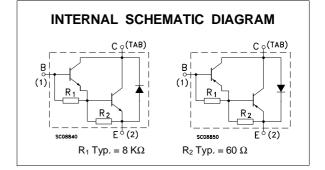
 LINEAR AND SWITCHING INDUSTRIAL EQUIPMENT

#### DESCRIPTION

The 2N6284 is a silicon epitaxial-base NPN power transistor in monolithic Darlington configuration mounted in Jedec TO-3 metal case. It is inteded for general purpose amplifier and low frequency switching applications.

The complementary PNP types is 2N6287.





#### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value		Unit	
		NPN	2N6284		
		PNP	2N6287		
V <sub>СВО</sub>	Collector-Base Voltage $(I_E = 0)$		100	V	
Vceo	Collector-Emitter Voltage (I <sub>B</sub> = 0)		or-Emitter Voltage (I <sub>B</sub> = 0) 100		
Vebo	Emitter-Base Voltage ( $I_C = 0$ )		$ltage (l_C = 0)$ 5		
Ι <sub>C</sub>	Collector Current		20		
I <sub>CM</sub>	Collector Peak Current		r Peak Current 40		
IB	Base Current		ase Current 0.5		Α
Ptot	Total Dissipation at $T_c \le 25$ °C		160	W	
T <sub>stg</sub>	Storage Temperature		-65 to 200	°C	
Tj	Max. Operating Junction Temperature		200	°C	

For PNP types voltage and current values are negative.

### THERMAL DATA

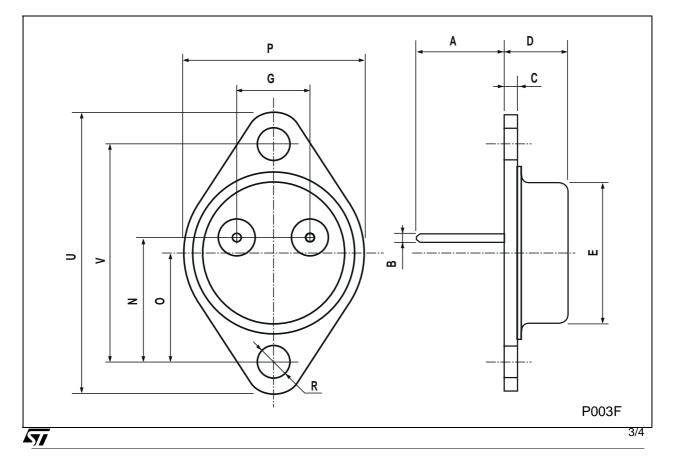
R <sub>thj-case</sub> Thermal Resistance Junction-case	Max	1.09	°C/W
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## **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
ICEV	Collector Cut-off	V <sub>CE</sub> = rated V <sub>CEO</sub>			0.5	mA
	Current ( $V_{BE} = -1.5V$ )	$V_{CE}$ = rated $V_{CEO}$ T <sub>c</sub> = 150 °C			5	mA
ICEO	Collector Cut-off Current ( $I_B = 0$ )	V <sub>CE</sub> = 50 V			1	mA
I <sub>EBO</sub>	Emitter Cut-off Current $(I_C = 0)$	$V_{EB} = 5 V$			2	mA
$V_{CEO(sus)^*}$	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 100 mA	100			V
V <sub>CE(sat)</sub> *	Collector-Emitter	$I_{C} = 10 \text{ A}$ $I_{B} = 40 \text{ mA}$			2	V
	Saturation Voltage	$I_{\rm C} = 20 \text{ A}$ $I_{\rm B} = 200 \text{ mA}$			3	V
V <sub>BE(sat)</sub> *	Base-Emitter Saturation Voltage	I <sub>C</sub> = 20 A I <sub>B</sub> = 200 mA			4	V
$V_{BE}*$	Base-Emitter Voltage	$I_{C} = 10 \text{ A}$ $V_{CE} = 3 \text{ V}$			2.8	V
h <sub>FE</sub> *	DC Current Gain	I <sub>C</sub> = 10 A V <sub>CE</sub> = 3 V	750		18000	
		$I_C = 20 A$ $V_{CE} = 3 V$	100			
h <sub>fe</sub>	Small Signal Current Gain	$I_C = 3 A$ $V_{CE} = 10 V$ $f = 1 KHz$	300			
Ссво	Collector Base	$I_E = 0$ $V_{CB} = 10$ V $f = 100$ KHz				
	Capacitance	for NPN types			400	рF
	duration - 300 us, duty cycle 1	for PNP types			600	рF

\* Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

DIM.	mm		inch			
Dim	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	11.00		13.10	0.433		0.516
В	0.97		1.15	0.038		0.045
С	1.50		1.65	0.059		0.065
D	8.32		8.92	0.327		0.351
E	19.00		20.00	0.748		0.787
G	10.70		11.10	0.421		0.437
N	16.50		17.20	0.649		0.677
Р	25.00		26.00	0.984		1.023
R	4.00		4.09	0.157		0.161
U	38.50		39.30	1.515		1.547
V	30.00		30.30	1.187		1.193



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